NSN 5961-01-275-2871

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-275-2871 **Inclosure Material:** Metal **Overall Length:** 1.702 inches **End Application:** 5895-01-205-0877 **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.552 inches and 0.562 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak off-state voltage and 200.0 repetitive peak reverse voltage and 300.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 35.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 0.5 watts any acceptable universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0